4V Drive Nch+Nch MOSFET SP8K22

●Structure

Silicon N-channel MOSFET

Features

- 1) Built-in G-S Protection Diode.
- 2) Small surface Mount Package (SOP8).

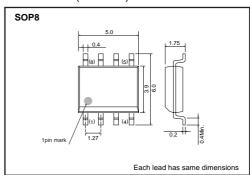
Applications

Power switching , DC / DC converter , Inverter

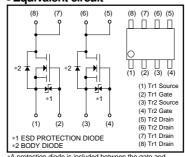
Packaging dimensions

	Package	Taping		
Type	Code	ТВ		
	Basic ordering unit (pieces)	2500		
SP8K22		0		

●Dimensions (Unit:mm)



●Equivalent circuit



A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

● Absolute maximum ratings (Ta=25°C)

< It is the same ratings for the Tr1 and Tr2.>

Parameter		Symbol	Limits	Unit	
Drain-source voltage		V_{DSS}	45	V	
Gate-source voltage		V_{GSS}	±20	V	
Drain current	Continuous	I _D	±4.5	Α	
	Pulsed	I _{DP} *1	±18	Α	
Source current (Body diode)	Continuous	I _S	1	Α	
	Pulsed	I _{SP} *1	18	Α	
Total power dissipation		P _{D *2}	2	W / TOTAL	
		Γ _D *2	1.4	W / ELEMENT	
Chanel temperature		T_{ch}	150	°C	
Range of Storage temperature		T_{stg}	-55 to +150	°C	
** ***					

^{*1} PW \leq 10 μ s, Duty cycle \leq 1%

^{*2} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	_	-	±10	μА	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _(BR) DSS	45	_	_	٧	I _D = 1mA, V _{GS} =0V
Zero gate voltage drain current	IDSS	_	_	1	μА	Vps= 45V, Vgs=0V
Gate threshold voltage	V _{GS (th)}	1.0	_	2.5	V	V _{DS} = 10V, I _D = 1mA
Static drain-source on-state resistance	R _{DS (on)} *	-	33	46	mΩ	I _D = 4.5A, V _{GS} = 10V
		_	41	57	mΩ	I _D = 4.5A, V _{GS} = 4.5V
		-	46	64	mΩ	ID= 4.5A, VGS= 4.0V
Forward transfer admittance	Y _{fs} *	3.5	_	_	S	V _{DS} = 10V, I _D = 4.5A
Input capacitance	Ciss	_	550	_	pF	V _{DS} = 10V
Output capacitance	Coss	_	140	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	70	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	_	12	_	ns	Vpp≒ 25V
Rise time	tr *	-	18	_	ns	I _D = 2.5A V _G s= 10V
Turn-off delay time	t _{d (off)} *	_	42	_	ns	$R_{i}=10\Omega$
Fall time	t _f *	_	12	_	ns	R _G =10Ω
Total gate charge	Qg *		6.8	9.6	nC	V _{DD} ≒25V, V _{GS} =5V
Gate-source charge	Q _{gs} *	-	2.0	_	nC] I _D = 4.5A
Gate-drain charge	Q _{gd} *	-	2.9	_	nC	$R_L=5.6\Omega$, $R_G=10\Omega$

^{*}Pulsed

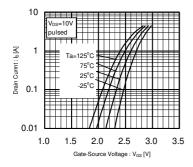
●Body diode characteristics (Source-drain) (Ta=25°C)

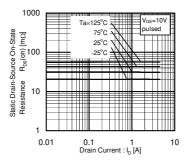
<It is the same characteristics for the Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V _{SD} *	_	_	1.2	V	$I_S=4.5A/V_{GS}=0V$

^{*} pulsed

•Electrical characteristic curves





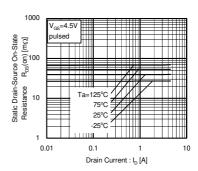
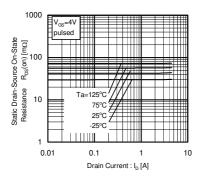
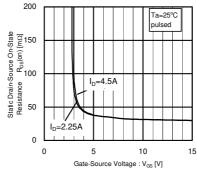


Fig.1 Typical Transfer Characteristics

Fig.2 Static Drain-Source On-State Resistance vs. Drain Current (1)

Fig.3 Static Drain-Source On-State Resistance vs. Drain Current (2)





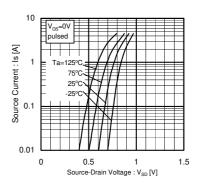
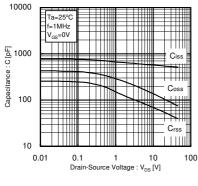
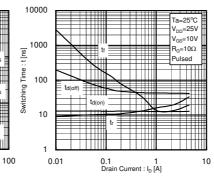


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (3)

Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

Fig.6 Source-Current vs. Source-Drain Voltage





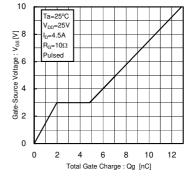


Fig.7 Typical capacitance vs. Source-Drain Voltage

Fig.8 Switching Characteristics

Fig.9 Dynamic Input Characteristics

Measurement circuits

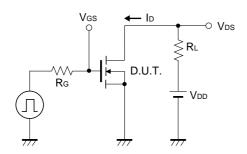


Fig.10 Switching Time Test Circuit

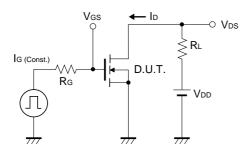


Fig.12 Gate Charge Test Circuit

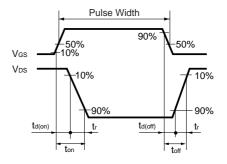


Fig.11 Switching Time Waveforms

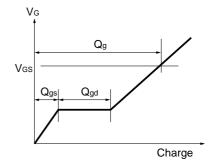


Fig.13 Gate Charge Waveform

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